

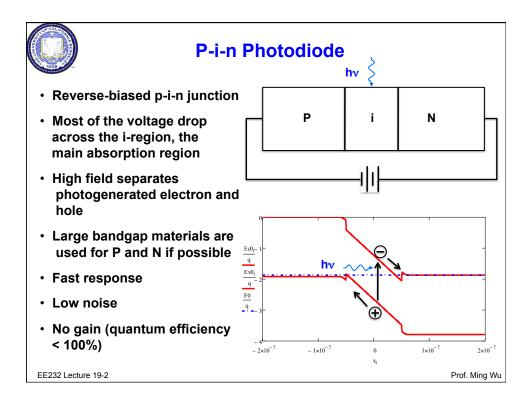
EE 232 Lightwave Devices Lecture 19: p-i-n Photodiodes and Photoconductors

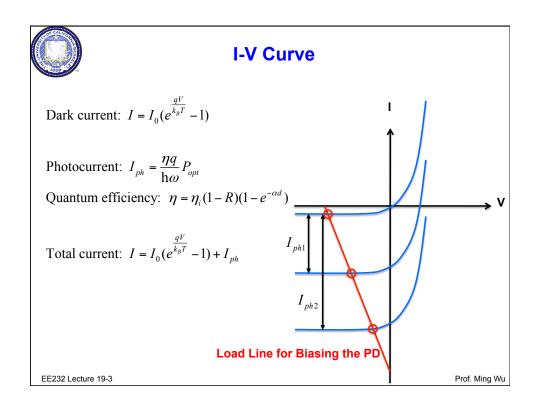
Reading: Chuang, Chap. 15 (2nd Ed)

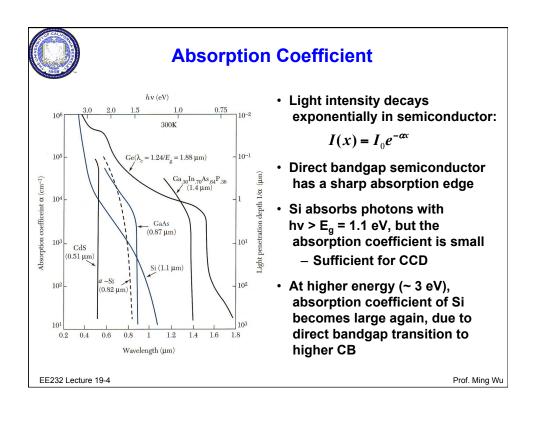
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University of California, Berkeley Electrical Engineering and Computer Sciences Dept.

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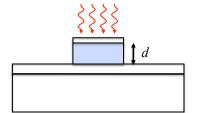


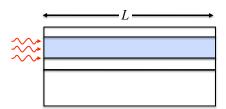






Two Types of p-i-n Photodiodes





Surface-Illuminated p-i-n

$$\eta = \eta_i (1 - R)(1 - e^{-\alpha d})$$

 η_i : internal quantum efficiency

R: reflectivity

d: absorption layer thickness

Waveguide p-i-n

$$\eta = \eta_i (1 - R)(1 - e^{-\Gamma \alpha L})$$

 η_i : internal quantum efficiency

R: reflectivity

 Γ : confinement factor

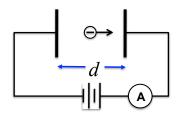
L: length of waveguide PD

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Ramo's Theorem



The current caused in external circuit by a moving charge q moving at a volocity v(t) in a parallel plate with a separation of d and a voltage bias of V is

$$i(t) = \frac{qv(t)}{d}$$

Proof:

Work done on the charge:

 $W = Force \times Displacement$

$$= qEdx = q\frac{V}{d}dx$$

Work provided by power supply:

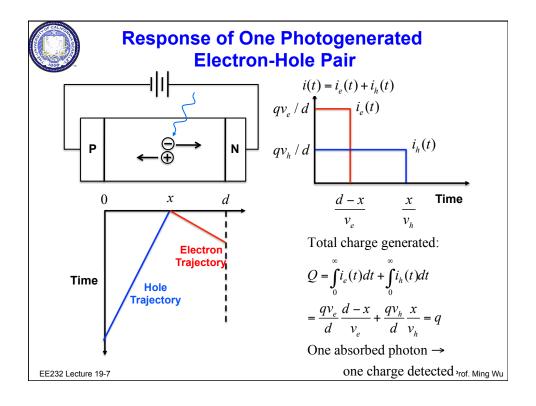
$$W = i(t)Vdt$$

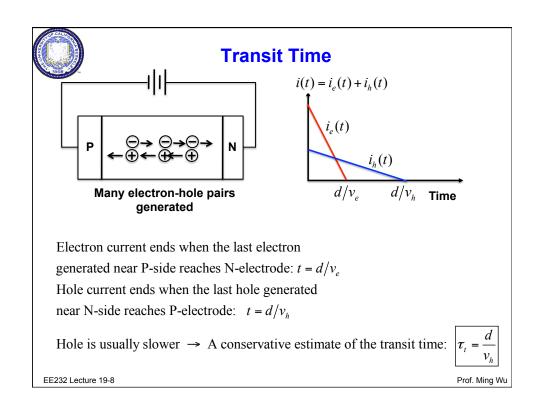
 \Rightarrow

$$i(t)Vdt = q\frac{V}{d}dx$$

$$i(t) = \frac{q}{d} \frac{dx}{dt} = \frac{qv(t)}{d}$$

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Total Response Time of p-i-n

(1) RC time:

$$\tau_{RC} = RC = R\frac{\varepsilon A}{d}$$
 (A: area of p-i-n)

(2) Transit time:

$$\tau_t = \frac{d}{v_h}$$

Total response time:

$$\tau = \tau_{RC} + \tau_t$$

$$f_{3dB} \approx \frac{1}{2\pi\tau}$$

Absorption layer thickness for optimum frequency response:

$$\tau = \tau_{RC} + \tau_t = \frac{R\varepsilon A}{d} + \frac{d}{v_h}$$

$$\tau \ge 2\sqrt{\left(\frac{R\varepsilon A}{d}\right)\left(\frac{d}{v_h}\right)}$$

$$f_{3dB} \approx \frac{1}{2\pi\tau} \leq \frac{1}{4\pi} \sqrt{\frac{v_h}{R\varepsilon A}} = f_{3dB,\text{max}}$$

Optimum bandwidth occurs when

$$\frac{R\varepsilon A}{d} = \frac{d}{v_{t}}$$

$$d_{optimum} = \sqrt{R\varepsilon A v_h}$$

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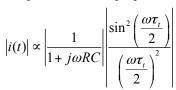
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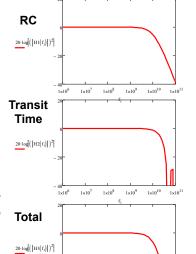


More Rigorous Analysis of p-i-n Response Time____

Small-signal analysis: assume the input light is modulated at frequency ω , the photocurrent is proportional to



The first term is single-pole response from RC, while the second term is the phase delay due to transit time response.



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Comparison of Numeric Examples

Example:

$$\tau_{\scriptscriptstyle RC}=14.4\,ps$$

$$\tau_t = 20 \, ps$$

$$f_{3dB} = \frac{1}{2\pi} \frac{1}{\tau_{RC} + \tau_t} = 4.6 \text{ GHz}$$

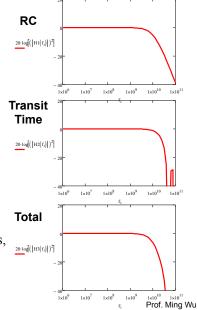
$$|i(t)| \propto \left| \frac{1}{1 + j\omega RC} \right| \frac{\sin^2\left(\frac{\omega \tau_t}{2}\right)}{\left(\frac{\omega \tau_t}{2}\right)^2} = |H(\omega)|$$

Solving
$$|H(\omega)| = \frac{1}{\sqrt{2}}$$
, $f_{3dB} = 9.7$ GHz

The discrepancy is smaller when RC dominates, and larger when transit time dominates.

(Transit time response has a sharp drop-off).

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Bandwidth-Efficiency Product

(1) For surface-illuminated p-i-n (assume AR coating: R=0%), in the extreme of thin absorbing layer and transit-time-dominated response:

$$\eta = \eta_i (1 - e^{-\alpha d}) \approx \eta_i (1 - (1 - \alpha d)) = \eta_i \alpha d$$

$$f_{3dB} \approx \frac{1}{2\pi} \frac{v_h}{d}$$

Bandwidth-efficiency product: $f_{3dB} \times \eta \approx \left(\frac{1}{2\pi} \frac{v_h}{d}\right) \left(\eta_i \alpha d\right) = \frac{\eta_i \alpha v_h}{2\pi}$

(2) On the other hand, the efficiency of waveguide p-i-n is

$$\eta = \eta_i (1 - e^{-\Gamma \alpha L}) \approx \eta_i \Gamma \alpha L$$

RC-limited bandwidth: $f_{3dB} \approx \frac{1}{2\pi} \frac{d}{R\varepsilon Lw}$

Bandwidth-efficiency product: $f_{3dB} \times \eta \approx \left(\frac{1}{2\pi} \frac{d}{R\varepsilon Lw}\right) (\eta_i \Gamma \alpha L) = \frac{\eta_i \Gamma \alpha d}{2\pi R\varepsilon w}$

⇒ In general, there is a bandwidth-efficiency trade-off

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Photoconductors

Dark current:

$$J_0 = \sigma_0 E = \left(n_0 q \mu_n + p_0 q \mu_p \right) E$$

Light illumination generate electron-hole pairs, increasing the conductivity:

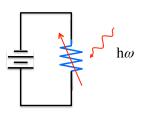
$$\frac{d\delta n}{dt} = G_0 - \frac{\delta n}{\tau_n}$$

Steady state: d/dt --> 0

$$\delta n = G_0 \tau_n$$

$$\Delta J = \delta n \cdot q \left(\mu_n + \mu_p \right) E$$

Equivalent Circuit



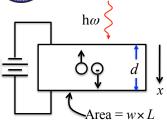
Photoconductor requires both contacts to be Ohmic and the semiconductor doping type to

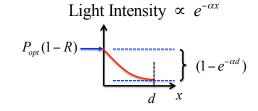
be the same.

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$$G_0 = \eta \frac{P_{opt}}{h\omega} \frac{1}{lwd}$$
: photocarrier generation rate $\left[\frac{1}{cm^3s}\right]$

$$\eta = \eta_i (1-R)(1-e^{-\alpha d})$$

R: reflectivity of photoconductor surface

 α : absorption coefficient

d: absorption lenght

 $e^{-\alpha d}$: fraction of light remains after absorption length d

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Photoconductive Gain

$$\Delta I = lw\Delta J = lw(G_0\tau_n q)(\mu_n + \mu_p)E$$

$$\Delta I = lw\left(\eta \frac{P_{opt}}{h\omega} \frac{1}{lwd}\tau_n\right) q(\mu_n + \mu_p)E$$

$$\Delta I \approx \eta \frac{P_{opt}}{h\omega} \frac{1}{d}\tau_n q(\mu_n E) = \eta P_{opt} \frac{q}{h\omega}\tau_n \frac{1}{d}v_n$$

$$\tau_t = \frac{d}{v_n} : \text{transit time}$$

$$\Delta I = \left(\eta P - \frac{q}{v_n}\right)\left(\frac{\tau_n}{v_n}\right)$$

$$\Delta I = \left(\eta P_{opt} \frac{q}{h\omega}\right) \left(\frac{\tau_n}{\tau_t}\right)$$

Photocurrent

Photoconductive Gain

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Analogy to Current Gain in Bipolar Transistor



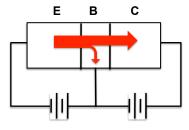
The current gain can also be expressed as

Current gain in bipolar transistor:

$$\beta = \frac{\tau_{rb}}{\tau_{t}}$$

 τ_t : transit time

 au_{rb} : carrier recombination lifetime in the base



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Frequency of Photoconductors

$$\frac{dN}{dt} = \eta \frac{P_{opt}}{\hbar \omega} \frac{1}{lwd} - \frac{N}{\tau_n}$$

Small signal response:

$$N = N_0 + N_1 e^{j\omega t}$$

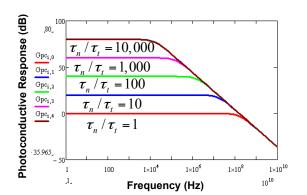
$$j\omega N_1 = \eta \frac{P_1}{\hbar \omega} \frac{1}{lwd} - \frac{N_1}{\tau_{...}}$$

$$j\omega N_1 = \eta \frac{P_1}{\hbar\omega} \frac{1}{lwd} - \frac{N_1}{\tau_n}$$

$$N_1 = \frac{\eta P_1}{\hbar\omega(lwd)} \frac{1}{j\omega + 1/\tau_n}$$

$$I_1 = J_1 l w = \left(N_1 q v_n \right) l w$$

$$\frac{I_1}{P_1} = \left(\frac{\eta q}{\hbar \omega}\right) \left(\frac{\tau_n}{\tau_t}\right) \frac{1}{j\omega \tau_n + 1}$$



= $(DC \text{ Quantum Efficiency}) \times (Photoconductive Gain}) \times$ (Normalized Frequency Response)

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